

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	5	("20020058361" "6153920" "6395587" "6593625" "6689671").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/15 17:07
L11	0	("6812074").URPN.	USPAT	OR	OFF	2005/02/15 17:13
L12	1	("6337500").PN.	USPAT	OR	OFF	2005/02/15 17:14
S1	14058	((438/142) or (438/149) or (438/151) or (438/154) or (438/162) or (438/163) or (438/180) or (438/181) or (438/184) or (438/185) or (438/197) or (438/199) or (438/218) or (438/221) or (438/229) or (438/230) or (438/231) or (438/232) or (438/294) or (438/296) or (438/299) or (438/301) or (438/303) or (438/308) or (438/478) or (438/479) or (438/481) or (438/514) or (438/517) or (438/518) or (438/519) or (438/520) or (438/527) or (438/528) or (438/542) or (438/543) or (438/545)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/11 16:26
S2	2512	S1 and (nmos or ((n:adj:type) near2 transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:27
S3	14058	((438/142) or (438/149) or (438/151) or (438/154) or (438/162) or (438/163) or (438/180) or (438/181) or (438/184) or (438/185) or (438/197) or (438/199) or (438/218) or (438/221) or (438/229) or (438/230) or (438/231) or (438/232) or (438/294) or (438/296) or (438/299) or (438/301) or (438/303) or (438/308) or (438/478) or (438/479) or (438/481) or (438/514) or (438/517) or (438/518) or (438/519) or (438/520) or (438/527) or (438/528) or (438/542) or (438/543) or (438/545)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/11 16:26

S4	2512	S3 and (nmos or ((n adj type) near2 transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:35
S5	1535	S4 and (((ion near implant\$5) or dop\$3) near10 ("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:35
S6	35	S5 and (((ion near implant\$5) or dop\$3) near5 ("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:50
S7	19	S6 and (defect\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:39
S8	557	(((ion near implant\$5) or dop\$3) near5 ("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon))) same (((ion near implant\$5) or dop\$3) near5 ("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:56
S9	225	S8 and (defect\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:51
S10	40	S9 and S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:51
S11	23	S10 not S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:51

S12	0	S11 and (nmos or ((n adj type) near2 transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 16:51
S13	58	((ion near implant\$5) or dop\$3) near ("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon)) same (((ion near implant\$5) or dop\$3) near5 ("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1))) and (nmos or ((n adj type) near2 transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:08
S14	18	S13 and S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:03
S15	40	S13 not S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:03
S16	20	((ion near implant\$5) or dop\$3) near ("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon)) near5 (((ion near implant\$5) or dop\$3) near5 ("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1))) and (nmos or ((n adj type) near2 transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:11
S17	40	((ion near implant\$5) or dop\$3) near ("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon)) near5 (((("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1))) and (nmos or ((n adj type) near2 transistor\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:14
S18	13	S17 not S15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:12

S19	77	((ion near implant\$5) or dop\$3) near (("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon))) same (((("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1))) and (nmos or ((n adj type) near2 transistor\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:22
S20	40	((ion near implant\$5) or dop\$3) near (("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon))) near5 (((("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1))) and (nmos or ((n adj type) near2 transistor\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:45
S21	172	defect\$1 near5 (((("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:21
S22	25	S21 same (((ion near implant\$5) or dop\$3) near10 (("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:06
S23	5	S22 and (nmos or ((n adj type) near2 transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 17:49
S24	8	S21 same (((ion near implant\$5) or dop\$3) near (("Si" or silicon) ("Ge" or germanium) or ("Ar" or argon) or (xe or xenon)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:06
S25	35	((ion near implant\$5) or dop\$3) same (defect\$1 near5 (((("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:33
S26	746	((ion near implant\$5) or dop\$3) near5 (((("SiGe" or (silicon adj germanium)) near (layer\$1 or film\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:34

S27	96	S26 and S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:34
S28	35	S27 and (nmos or ((n:adj type) near2:transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:48
S29	61	S27 not S28	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 18:49